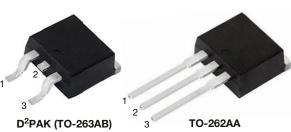
www.vishay.com

VS-20CTH03S-M3, VS-20CTH03-1-M3

Vishay Semiconductors

Hyperfast Rectifier, 2 x 10 A FRED Pt[®]



Base common common cathode cathode 02 2 Common ⁽⁾ 3 10 Common Anode cathode Anode Anode cathode

VS-20CTH03S-M3

2

1 Ó

Base

02

VS-20CTH03-1-M3

d 3

Anode

PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 x 10 A				
V _R	300 V				
V _F at I _F	0.85 V				
t _{rr} max.	35 ns				
T _J max.	175 °C				
Package	D ² PAK (TO-263AB), TO-262AA				
Circuit configuration	Common cathode				

FEATURES

- Hyperfast recovery time
- Low forward voltage drop
- Low leakage current
- 175 °C operating junction temperature
- · Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

Vishay Semiconductors 300 V series are the state of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop and hyperfast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, DC/DC converters as well as freewheeling diode in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS						
PARAMETER		SYMBOL	TEST CONDITIONS	MAX.	UNITS	
Peak repetitive reverse voltage		V _{RRM}		300	V	
	per diode		T _C = 160 °C	10		
Average rectified forward current	per device	IF(AV)		20	А	
Non-repetitive peak surge current		I _{FSM}	T _J = 25 °C	120		
Operating junction and storage ter	nperatures	T _J , T _{Stg}		-65 to +175	°C	

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	300	-	-			
Forward voltage V _F	I _F = 10 A	-	1.05	1.25	V			
	۷F	I _F = 10 A, T _J = 125 °C	-	0.85	0.95			
Povorao lookogo ourront		V _R = V _R rated	-	-	20			
Reverse leakage current		$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	6	200	μA		
Junction capacitance	CT	V _R = 300 V	-	30	-	pF		
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	8	-	nH		

Revision: 27-Nov-2018

Document Number: 96386

For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishav.com/doc?91000

1



COMPLIANT

HALOGEN

FREE



www.vishay.com

Vishay Semiconductors

DYNAMIC RECOVERY CHARACTERISTICS ($T_C = 25$ °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS		
		$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t =$	50 A/µs, V _R = 30 V	-	-	35		
	+	$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t =$	$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 100 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$		-	30		
Reverse recovery time	t _{rr}	T _J = 25 °C		-	31	-	ns	
		T _J = 125 °C		-	42	-		
Peak recovery current	1	T _J = 25 °C	I _F = 10 A dI _F /dt = 200 A/μs V _B = 200 V	-	2.4	-	А	
Peak recovery current	I _{RRM}	T _J = 125 °C		-	5.6	-	A	
Reverse recovery charge	<u> </u>	T _J = 25 °C		-	36	-		
	Q _{rr}	T _J = 125 °C		-	120	-	nC	

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T _J , T _{Stg}		-65	-	175	°C	
Thermal resistance, junction to case per diode	R _{thJC}		-	-	1.5	°C/W	
Weight			-	2.0	-	g	
weight			-	0.07	-	oz.	
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)	
Marking daviag		Case style D ² PAK (TO-263AB)		20CT	H03S		
Marking device		Case style TO-262AA		20CT	H03-1		

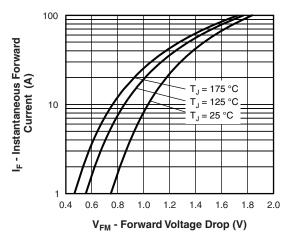


Fig. 1 - Maximum Forward Voltage Drop Characteristics

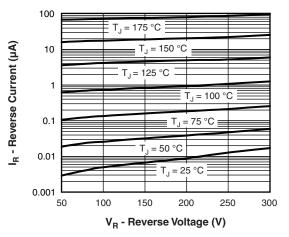


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



VS-20CTH03S-M3, VS-20CTH03-1-M3

Vishay Semiconductors

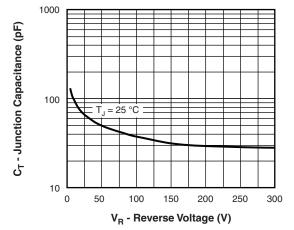


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

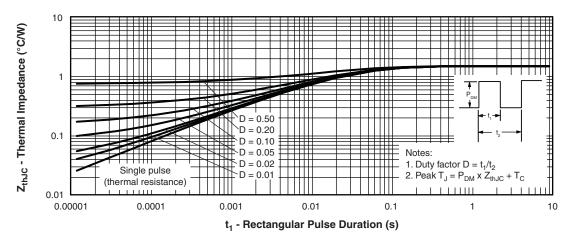
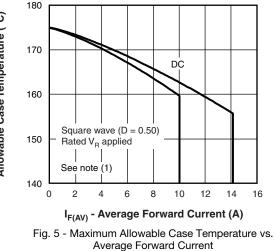
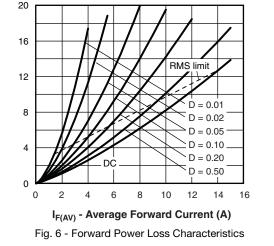


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

Average Power Loss (W)





Revision: 27-Nov-2018

Document Number: 96386

For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

VS-20CTH03S-M3, VS-20CTH03-1-M3

T_J = 125 °C

= 25 °C

dl_F/dt (A/µs)

Fig. 8 - Typical Stored Charge vs. dl_F/dt

1000

100

10

100

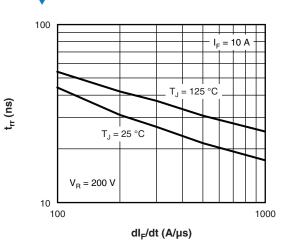
Q_{rr} (nC)



 $I_{r} = 10 A$

V_R = 200 V

1000



www.vishay.com

Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

Note

SHA

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

Pd = forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6); Pd_{REV} = inverse power loss = $V_{R1} \times I_R$ (1 - D); I_R at V_{R1} = rated V_R

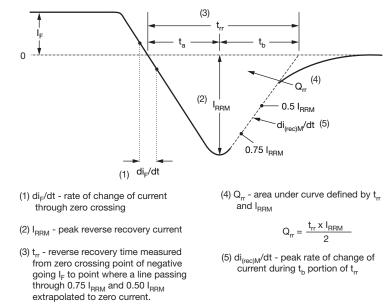
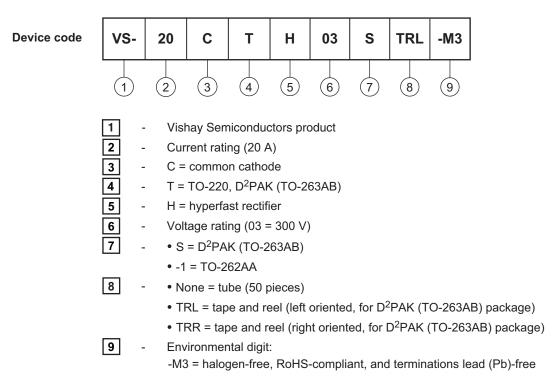


Fig. 9 - Reverse Recovery Waveform and Definitions



ORDERING INFORMATION TABLE

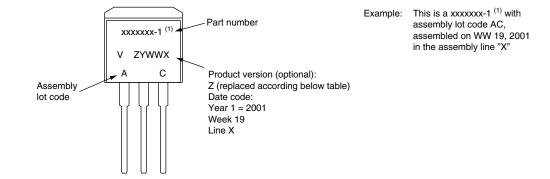
www.vishay.com



LINKS TO RELATED DOCUMENTS					
Dimensions -	D ² PAK (TO-263AB)	www.vishay.com/doc?96164			
Dimensions	TO-262AA	www.vishay.com/doc?96165			
Part marking information -	D ² PAK (TO-263AB)	www.vishay.com/doc?95444			
	TO-262AA	www.vishay.com/doc?95443			
Packaging information	D ² PAK (TO-263AB)	www.vishay.com/doc?96424			



TO-262



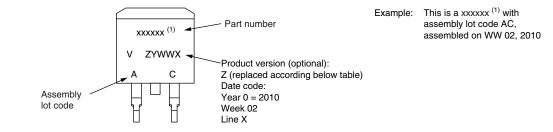
Note

⁽¹⁾ If part number contain "H" as last digit, product is AEC-Q101 qualified

ENVIRONMENTAL NAMING CODE (Z)	PRODUCT DEFINITION
A	Termination lead (Pb)-free
В	Totally lead (Pb)-free
E	RoHS-compliant and termination lead (Pb)-free
F	RoHS-compliant and totally lead (Pb)-free
М	Halogen-free, RoHS-compliant and termination lead (Pb)-free
Ν	Halogen-free, RoHS-compliant and totally lead (Pb)-free
G	Green



D²PAK



Note

⁽¹⁾ If part number contain "H" as last digit, product is AEC-Q101 qualified

ENVIRONMENTAL NAMING CODE (Z)	PRODUCT DEFINITION
A	Termination lead (Pb)-free
В	Totally lead (Pb)-free
E	RoHS-compliant and termination lead (Pb)-free
F	RoHS-compliant and totally lead (Pb)-free
М	Halogen-free, RoHS-compliant, and termination lead (Pb)-free
N	Halogen-free, RoHS-compliant, and totally lead (Pb)-free
G	Green

D²PAK

DIMENSIONS in millimeters and inches



otated	90	Ű
<u>Scale</u>	<u>ə:</u> 8	:1

SYMBOL	MILLIM	ETERS	INC	HES	NOTES	
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
А	4.06	4.83	0.160	0.190		
A1	0.00	0.254	0.000	0.010		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
с	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2]

SYMBOL		MILLIM	ETERS	INC	HES	NOTES
511	BOL	MIN.	MAX.	MIN.	MAX.	NOTES
C)1	6.86	8.00	0.270	0.315	3
E	Ξ	9.65	10.67	0.380	0.420	2, 3
E	1	7.90	8.80	0.311	0.346	3
	e	2.54 BSC		0.100 BSC		
ł	1	14.61	15.88	0.575	0.625	
I	L	1.78	2.79	0.070	0.110	
L	.1	-	1.65	-	0.066	3
L	.2	1.27	1.78	0.050	0.070	
L	.3	0.25 BSC		0.010	BSC	
L	.4	4.78	5.28	0.188	0.208	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Datum A and B to be determined at datum plane H

⁽⁶⁾ Controlling dimension: inches

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-263AB

Revision: 13-Jul-17

1

Document Number: 96164

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



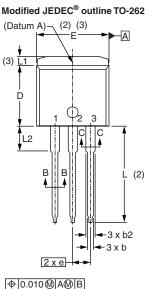
Outline Dimensions

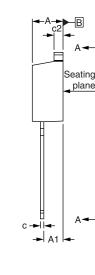


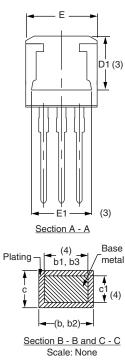
Vishay Semiconductors

TO-262AA

DIMENSIONS in millimeters and inches







1	maan	meath	TRAT



Diodes 1. - Anode (two die)/open (one die) 2., 4. - Cathode 3. - Anode

Lead assignments

SYMBOL	MILLIMETERS		INCHES		
	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	2.03	3.02	0.080	0.119	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100 BSC		
L	13.46	14.10	0.530	0.555	
L1	-	1.65	-	0.065	3
L2	3.56	3.71	0.140	0.146	

 ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the state back. the outmost extremes of the plastic body

(3) Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only (5)

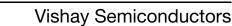
Controlling dimension: inches

(6) Outline conform to JEDEC® TO-262 except A1 (max.), b (min., max.), b1 (min.), b2 (max.), c (min.), c1(min.), c2 (max.), D (min.), E (max.), L1 (max.), L2 (min., max.)

Revision: 30-Nov-17

1

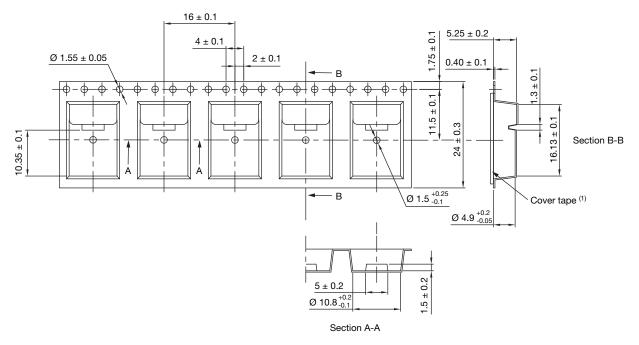
For technical questions within your region: DiodesAmericas@vishav.com, DiodesAsia@vishav.com, DiodesEurope@vishav.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishav.com/doc?91000





D²PAK (TO-263AB)

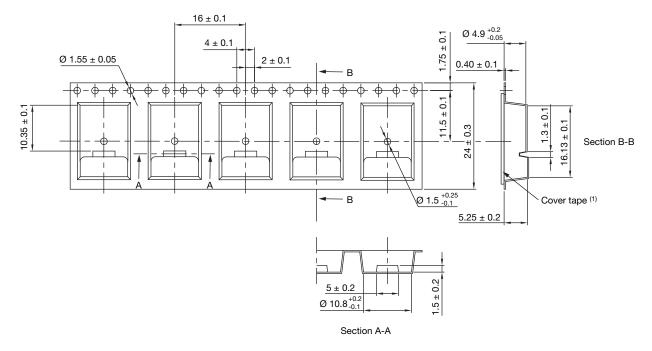
CARRIER TAPE FOR TAPE AND REEL LEFT in millimeters



Note

 $^{\left(1\right)}$ For dimensions, see next pages

CARRIER TAPE FOR TAPE AND REEL RIGHT in millimeters



Note

⁽¹⁾ For dimensions, see next pages

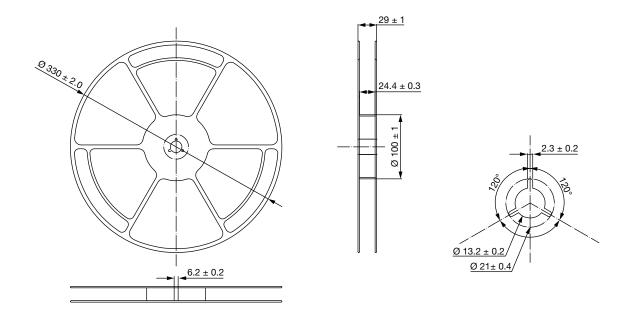
Revision: 13-Oct-17 Document Number: 96424 1 For technical questions within your region: DiodesAmericas@vishav.com, DiodesAsia@vishav.com, DiodesEurope@vishav.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishav.com/doc?91000



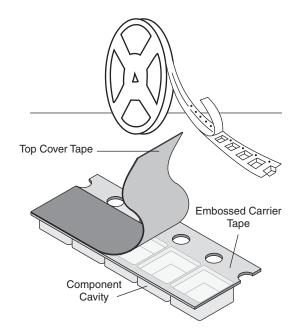
Packaging Information

Vishay Semiconductors

REEL FOR CARRIER TAPE in millimeters



CARRIER TAPE AND REEL PACKAGING D²PAK (TO-263AB)

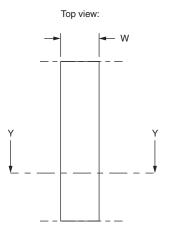


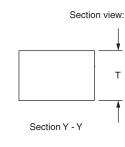
Packaging Information

Vishay Semiconductors



COVER TAPE FOR CARRIER TAPE in millimeters





APPLICATION	COVER TAPE WIDTH W	COVER TAPE THICKNESS T	CARRIER TAPE WIDTH	MATERIAL
D ² PAK (TO-263AB)	21.3 ± 0.1	0.060 ± 0.01	24	Antistatic/treated/transparent/polyester



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Rectifiers category:

Click to view products by Vishay manufacturer:

Other Similar products are found below :

D91A DA24F4100L DD89N1600K-A DD89N16K-K RL252-TP DSEI2X30-06C 1N4005-TR BAV199-TP UFS120Je3/TR13 JANS1N6640US DD89N16K DD89N16K-A 481235F 067907F MS306 ND104N08K SPA2003-B-D-A01 US2JFL-TP UFS105Je3/TR13 A1N5404G-G ACGRA4007-HF ACGRB207-HF RF301B2STL RF501B2STL UES1302 BAV199E6433HTMA1 ACGRC307-HF ACEFC304-HF JANTXV1N5660A UES1106 GS2K-LTP D126A45C D251N08B SCHJ22.5K SM100 SCPA2 SDHD5K STTH20P035FP VS-8EWS12S-M3 VS-12FL100S10 ACGRA4001-HF MUR420GP-TP 1N5404GP-E3/54 ND89N08K D1821SH45T PR D1251S45T JANTX1N3890 SKN20/16 SKN70/16 1N3660R